Casim ir-Polder force density between an atom and a conducting wall

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In this paper we calculate the C asim ir-Polder force density (force per unit area acting on the elements of the surface) on a metallic plate placed in front of a neutral atom. To obtain the force density we use the quantum operator associated to the electromagnetic stress tensor. We explicitly show that the integral of this force density over the plate reproduces the total force acting on the plate. This result shows that, although the force is obtained as a sum of surface element-atom contributions, the stress-tensor method includes also nonadditive components of Casim ir-Polder forces in the evaluation of the force acting on a macroscopic object.

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I. INTRODUCTION

A surprising prediction of quantum electrodynamics is the existence of forces of electrom agnetic nature between pairs of metallic uncharged objects. This kind of eects were rst predicted theoretically by H B G . Casim ir and D. Polder in 1948. In two di erent articles (the form er of Casim ir alone [1], the latter of both [2]), the existence of forces between two at parallel neutral m etallic plates, the so called Casim ir e ect, between a neutral atom and a wall and between two neutral atoms is predicted. The origin of these forces is comm only attributed to the properties of the vacuum state of the electrom agnetic eld, that is the state of minimum energy, and in particular to the fact that the vacuum energy depends on the boundary conditions characterizing the system [3, 4]. A Ithough these forces are very tiny, they have been measured with rem arkable precision. The rst successful precision experim ents were on the wall-sphere system [5, 6]. Next, the force between a neutralatom and a wallwas observed [7, 8, 9], as well as between two metallic neutral parallel plates [10, 11]. For the atom -atom Casim ir-Polder force, only indirect evidences of their existence have been yet obtained.

In this paper we consider a neutral atom in front of a metallic, perfectly conducting plate. The force on the atom in this con guration has been calculated by C asim ir and P older [2]. We focus our attention on the plate and in Section II we calculate, using the quantum electromagnetic stress tensor, the force acting upon each surface element of the plate. Then, in Section III we show that the integral of this force density over the surface of the plate equals the opposite of the force experienced by the atom. This conducts us to a concluding enquiry on the connection between the stress-tensorm ethod and the well-known nonadditivity of C asim ir-P older forces. We conclude that the stress-tensorm ethod has the great advantage of autom atically including many-body contri-

butions of the Casim ir-Polder forces.

II. THE FORCE DENSITY ON THE WALL

The Casim ir-Polder interaction between a neutral atom and a metallic uncharged wall yields an attractive atom -wall force. The value of this force was originally calculated using second order perturbation theory and the minimal coupling Hamiltonian, obtaining

$$F_A (d) = \frac{3 \sim c}{2 d^5}$$
 (1)

where d is the atom -wall distance, is the static polarizability of the atom and the minus sign indicates that the force is attractive [2]. The expression (1) is valid in the so-called far zone de ned by $d>>c=!_0$, $!_0$ being a typical atom ic frequency.

We now focus our attention on the wall. Being the wall an extended object, it makes sense to ask ourselves which is the force acting on each surface element of the metallic plate. To answer this question we use the quantum operator associated to the classical electrom agnetic stress tensor. This method was widely used by Barton in his works about uctuations of Casim ir-Polder forces [12, 13]. In classical electrodynamics, the stress tensor is defined as

$$S_{ij}(r) = \frac{1}{4}^{h} E_{i}(r)E_{j}(r) + B_{i}(r)B_{j}(r)$$

$$\frac{1}{2} ij E^{2}(r) + B^{2}(r)$$
(2)

where E $_{\rm i}$ and B $_{\rm i}$ are components of the electric and m agnetic eld, i and j assuming the values 1;2;3 corresponding, respectively, to x, y and z. As it is well known [14], this tensor perm its to calculate the force on a volume V . The i-th component of this force is given by

$$F_{i} = \int_{V}^{Z} dV f_{i} = \int_{S_{j=1}}^{I} dA_{j} S_{ij}$$
 (3)

where the last integral is extended over the surface S enclosing the volume V . If we assume the wall to be

located at z=L and to have an in nitesimal perpendicular extension dz, the z component of the force on an in nitesimal parallelepiped dxdydz representing the surface element centered in the point (x;y) on the plate is given by

$$(x;y) = S_{zz}(x;y;L + dz) S_{zz}(x;y;L)$$
 (4)

E quations (2) and (4) are classical. To obtain the quantum operator associated to the stress tensor we simply replace the components E $_{\rm i}$ and B $_{\rm i}$ of the electric and magnetic elds with the corresponding quantum operators. In the Schrödinger representation, we have

E (r) =
$$i \frac{X}{V} \frac{r}{2 \sim !_{k}} (a_{kj} \quad a_{kj}^{y}) f(kj;r)$$
 (5)

$$B(r) = \begin{cases} X & \frac{1}{2 - c^2} \\ \frac{1}{V!_k} & (a_{kj} + a_{kj}^y) r & f(kj;r) \end{cases}$$
 (6)

where the functions f(k j; r) (assumed real) are the eld modes corresponding to the boundary conditions characterizing the system . In our case, the presence of a metallic surface located in z=L can be taken into account by considering two metallic boxes (the former on the left, the latter on the right of the wall) having in common one side on this plane. At the end of the calculations, we send to in nity the length of the three edges of the two cavities. For example, the cavity on the right of the plane is the parallelepiped

$$\frac{L_1}{2} < x < \frac{L_1}{2}$$
 $\frac{L_1}{2} < y < \frac{L_1}{2}$ L < z < L₁ (7)

where $L_1 > L$ and the volume of the cavity is $V = L_1^2$ (L L_1). The mode functions for this box have components

$$f_{x}(kj;r) = P = \frac{h}{8(e_{kj})_{x} \cos k_{x}} \times + \frac{L_{1}}{2} \sin k_{y} y + \frac{L_{1}}{2} \sin k_{z} z L$$

$$f_{y}(kj;r) = P = \frac{h}{8(e_{kj})_{y} \sin k_{x}} \times + \frac{L_{1}}{2} \cos k_{y} y + \frac{L_{1}}{2} \sin k_{z} z L$$

$$f_{z}(kj;r) = P = \frac{h}{8(e_{kj})_{z} \sin k_{x}} \times + \frac{L_{1}}{2} \sin k_{y} y + \frac{L_{1}}{2} \sin k_{z} z L$$

$$(8)$$

where $e_{k\,j}$ are polarization unit vectors and the allowed values of k have components

$$k_x = \frac{1}{L_1}$$
; $k_y = \frac{m}{L_1}$; $k_z = \frac{n}{L_1 L}$; $l_z m$; $n = 0;1;...$

As mentioned before, at the end we take the $\lim it L_i L_1 ! + 1$.

Since we have replaced the classical stress tensor with a quantum operator we have to replace the di erence on the RHS of (4) with a dierence between quantum averages of the stress tensor operator. These averages must be calculated on quantum states re ecting the dierent physical situation at the two sides of the wall: the bare vacuum on its left side and the atom on the right side, which we assume located at $r_A = (0;0;D)$, with D > L. On this basis, we take the bare vacuum state of the electrom agnetic eld for the space on the left side of the wall, which we indicate with Di. As for the right side of the wall, we use the dressed vacuum state, that is the vacuum state corrected by the presence of the atom. We obtain this state at the lowest signi cant order in the atom - eld interaction. It is very convenient to describe the atom - eld interaction using an e ective interaction Ham iltonian, valid both in the near and the far zone,

given by [15]

$$W = \frac{1}{2} X_{kk^{0}jj^{0}} (k) E_{kj} (r_{A}) E_{k^{0}j^{0}} (r_{A})$$
 (10)

where

$$E_{kj}(r) = i \frac{2^{-1}_{k}}{V} (a_{kj} a_{kj}^{y}) f(kj;r)$$
 (11)

are the Fourier components of the electriceld (5) and (k) is the dynamical polarizability of the atom. Using rst order perturbation theory with the interaction (10), we get the dressed vacuum state as

where

$$jli = \frac{X}{V}_{kk^{0}jj^{0}} (k) \frac{p}{k+k^{0}} f(k;j;r_{A}) f(k;j^{0};r_{A}) jl_{kj} l_{k^{0}j^{0}} i$$
(13)

 $\mathbf{1}_{k\,j}$ denoting the presence of a photon with wavevector k and polarization j.

Thus, the force density is expressed by

$$(x;y) = h0 + (x;y) + h0 + (x;$$

where, for simplicity of notations,

The explicit expression of the operator S (x;y) can be simply obtained from (2) in the following form

$$S(x;y) = S_{zz}(x;y;L)$$
: (15)

$$S(x;y) = \frac{2^{-c}}{V} X A(kj)A(k^{0}j^{0}) (a_{kj} - a_{kj}^{y}) (a_{k^{0}j^{0}} - a_{k^{0}j^{0}}^{y}) +$$

$$+ B(kj;k^{0}j^{0}) (a_{kj} + a_{kj}^{y}) (a_{k^{0}j^{0}} + a_{k^{0}j^{0}}^{y}) :$$
(16)

w here

$$A (kj) = {p \over k} (e_{kj})_z \sin k_x + \frac{L_1}{2} \sin k_y + \frac{L_1}{2} i$$
(17)

and

U sing eq. (12), from (14) we obtain at the $\,$ rst order in ,

$$(x;y) = 2h0$$
\$ $(x;y)$ $1i = 2S_{01}(x;y)$: (19)

Using (13) and (16), we obtain

$$(x;y) = \frac{8 - C}{V^{2}} X (k) \frac{p \frac{k^{0}}{k^{0}}}{k + k^{0}} f(k j; r_{A}) \qquad f(k j^{0}; r_{A})$$

$$h \qquad i$$

$$A(k j) A(k^{0} j^{0}) + B(k j; k^{0} j^{0}) : \qquad (20)$$

Our system has a cylindrical sym m etry around the axis

perpendicular to the wall and passing through the atom . Thus, being P=(0;0;L) the point comm on to this axis and the wall, the force density depends only on the distance of a point of the plate from P. In the far zone, where the dynamical polarizability (k) is replaced with its static value, we obtain

$$() = \frac{\sim_{C}}{4^{-3}} \begin{bmatrix} Z_{+1} & h \\ dx & I_{1}^{2}(x) + 2I_{2}^{2}(x) + I_{3}^{2}(x) + I_{4}^{2}(x) \end{bmatrix}$$
 (21)

where

where J (x) is a Bessel function of the rst kind of order [16]. Making use of known properties of Bessel functions [17], we nally obtain the following expression for the force density

$$() = \frac{\sim c}{4^{-2}} \frac{17d^2 + 10^{-2}}{(d^2 + 2)^{\frac{9}{2}}}$$
 (23)

where d=D L is the atom -wall distance. It is im mediate to see that the force density is vanishing in both \lim its d!+1 (atom in nitely distant from the wall) and !+1 (surface element of the wall in nitely distant from the atom).

III. THE INTEGRAL OF THE FORCE DENSITY AND NONADDITIVITY OF CASIM IR -POLDER FORCES

Once the force density (23) has been obtained, we can integrate it over the surface of the wall in order to obtain the total force F_W (d) experienced by the wall. We easily obtain

which is the opposite of the force F_{A} (d) acting on the atom given by equation (1).

This result may appear contradicting the wellestablished fact that C asim ir-Polder forces are not additive [3, 18, 19]. For example, in the case of three atom s it is known that the force on one of them is not simply the sum of the forces due to the other two atoms separately. The system we are considering, and in particular the fact that we are focusing our attention on elements of the plate, raises a sim ilar problem. Suppose we have the atom in front of a single elem ent of the plate and that we calculate the force acting on this surface element. This force, obviously, will depend on the coordinate of the elem ent. Due to the nonadditivity of Casim ir-forces, we expect that its integral over the entire plate should not give the total force, since the force on the wall should also contain three-body components involving the atom and two di erent elem ents of the wall (all these com ponents are proportional to). The solution of this seem ingly contradictory point is related to the use of the stresstensor m ethod. The stress tensor operator (2) contains in its very expression the electric and magnetic eld operators. These eld operators, given by equations (5) and (6), involve the mode function f(kj;r), which are taking into account the presence of the entire plate. As a consequence, we claim that the use of the operator S (x; y)

to calculate the force density on a surface element of the wall answers the following question: if we have a neutral atom in front of a conducting wall, what is the force acting on a surface element of the wall in the presence of the entire plate? On the basis of this consideration, the integral of such contribution over the wall surface must give the correct value for the total force, as we have explicitly shown. Hence, all many-body contributions to the atom -surface element Casim ir-Polder force which are proportional to are already included in our result (23). M oreover, we wish to stress that from the density of the force we can obtain much more information on the effects of the atom -wall Casim ir-Polder interaction, such as torques or stresses on the wall due to the presence of the atom. These e ects may be relevant in the recently proposed technological application of C asim ir forces [21].

IV. CONCLUSIONS

In this paper we have considered the Casim ir-Polder interaction between a neutral atom and a neutral conducting wall. We have calculated, using the quantum operator associated with the classical electrom agnetic stress tensor, the force density on the plate, that is the force acting on each surface element of the wall. We have shown that the integral of this density gives the correct result for the total forced acting on the plate, i.e. the opposite of the force on the atom . This shows that our method based on the stress tensor, usually used for macroscopic bodies, enables to include easily, at the order considered, all nonadditive components of Casim ir-Polder forces between the atom and two ormore plate elements. In fact, the force calculated for each surface element is indeed the force acting on it in the presence of the entire plate. This happens because the stress tensor in its very de nition contains the modes of the electrom agnetic eld, which take into account the presence of all macroscopic bodies in the system.

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